NSN 5961-01-056-2832

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View Online at https://aerobasegroup.com/nsn/5961-01-056-2832 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.213 inches **Overall Diameter:** Between 0.667 inches and 0.687 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-61 **Mounting Method:** Threaded stud **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 80.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage, static, collector open **Power Rating Per Characteristic:** 115.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: